



Jan-Philipp Koester (Autor)

Design, simulation and analysis of laterally-longitudinally non-uniform edge-emitting GaAs-based diode lasers

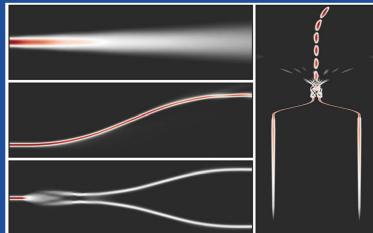


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Design, simulation and analysis of
laterally-longitudinally non-uniform
edge-emitting GaAs-based diode lasers



Innovationen mit Mikrowellen & Licht

Jan-Philipp Koester

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